

July 1994

## Dual, Ultra Low Power Operational Amplifier

### Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Low Supply Current at  $V_S = +5V \dots (+25^\circ C)$  **160 $\mu A$  (Max)**  
(Full) **200 $\mu A$  (Max)**
- Wide Supply Voltage Range . . . . . **Single 3V to 30V or Dual  $\pm 1.5$  to  $\pm 15V$**
- High Slew Rate . . . . . **0.8V/ $\mu s$  (Min)**  
**1.5V/ $\mu s$  (Typ)**
- High Gain . . . . . **20kV/V (Min)**  
**75kV/V (Typ)**
- Low Noise (1kHz) . . . . . **20nV/ $\sqrt{Hz}$  (Typ)**
- 100% Tested at  $\pm 15V$  and  $+5V, 0V$  Power Supplies
- Unity Gain Stable
- Dielectric Isolation

### Applications

- Portable Instruments
- Meter Amplifiers
- Telephone Headsets
- Microphone Amplifiers
- Instrumentation
- For Further Design Ideas See Application Note AN544

### Description

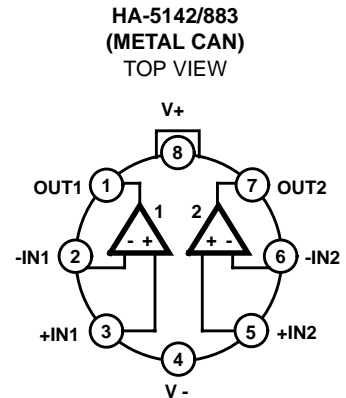
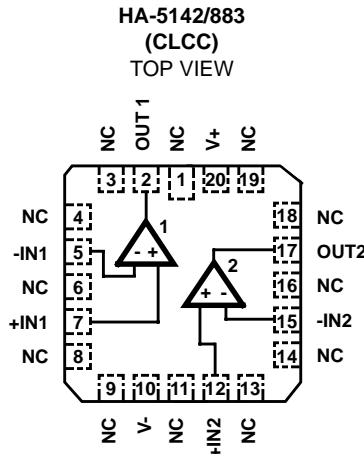
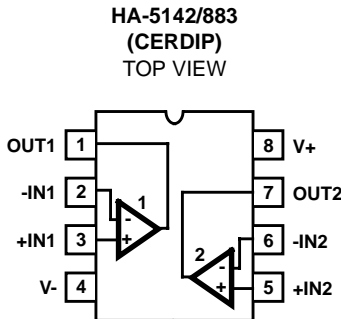
The HA-5142/883 dual, ultra-low power operational amplifier provides AC and DC performance characteristics similar to, or better than most general purpose amplifiers while only drawing 1/30 of the supply current of most general purpose amplifiers. This amplifier is well suited to applications which require low power dissipation and good electrical characteristics.

The HA-5142/883 provides accurate signal processing by virtue of their low input offset voltage (6mV), low input bias current (100nA), high open loop gain (20kV/V) and low noise (20nV/ $\sqrt{Hz}$ ). These characteristics coupled with a 1.5V/ $\mu s$  slew rate and a 24kHz bandwidth make the HA-5142/883 ideal for use in low power instrumentation, audio amplifier and active filter designs.

### Ordering Information

| PART NUMBER  | TEMPERATURE RANGE | PACKAGE             |
|--------------|-------------------|---------------------|
| HA7-5142/883 | -55°C to +125°C   | 8 Lead CerDIP       |
| HA2-5142/883 | -55°C to +125°C   | 8 Pin Can           |
| HA4-5142/883 | -55°C to +125°C   | 20 Lead Ceramic LCC |

### Pinouts



# Specifications HA-5142/883

## Absolute Maximum Ratings

|  |                                 |
|--|---------------------------------|
| Voltage Between V+ and V- Terminals    | 35V                             |
| Differential Input Voltage             | 7V                              |
| Voltage at Either Input Terminal       | V+ to V-                        |
| Output Current                         | Full Short Circuit Protection   |
| Output Current Duration                | Indefinite                      |
|  | One Amplifier Shorted to Ground |
| Junction Temperature (T <sub>J</sub> ) | +175°C                          |
| Storage Temperature Range              | -65°C to +150°C                 |
| ESD Rating                             | <2000V                          |
| Lead Temperature (Soldering 10s)       | +300°C                          |

## Thermal Information

|  |               |               |
|--|---------------|---------------|
| Thermal Resistance   | $\theta_{JA}$ | $\theta_{JC}$ |
| CerDIP Package   | 115°C/W       | 28°C/W        |
| Ceramic LCC Package  | 65°C/W        | 15°C/W        |
| Metal Can Package  | 155°C/W       | 67°C/W        |
| Package Power Dissipation Limit at +75°C for T <sub>J</sub> ≤ +175°C |               |               |
| CerDIP Package   |               | 870mW         |
| Ceramic LCC Package  |               | 1.54W         |
| Metal Can Package  |               | 645mW         |
| Package Power Dissipation Derating Factor Above +75°C                |               |               |
| CerDIP Package   |               | 8.7mW/°C      |
| Ceramic LCC Package  |               | 15.4mW/°C     |
| Metal Can Package  |               | 6.5mW/°C      |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Operating Conditions

|                             |                               |                               |
|-----------------------------|-------------------------------|-------------------------------|
| Operating Temperature Range | -55°C to +125°C               | $V_{INCM} \leq 1/2 (V+ - V-)$ |
| Operating Supply Voltage    | ±1.5V to ±15V<br>or 3V to 30V | $R_L \geq 50k\Omega$          |

**TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Tested at: R<sub>SOURCE</sub> = 100Ω, R<sub>LOAD</sub> = 500kΩ, V<sub>OUT</sub> = 0V, Unless Otherwise Specified.

Subscript 1 Refers to Supply Voltages (V±) = ±15V, Subscript 2 Refers to V+ = 5.0, V- = 0V

| PARAMETERS           | SYMBOL            | CONDITIONS  | GROUP A<br>SUBGROUPS | TEMPERATURE   | LIMITS |     | UNITS |
|----------------------|-------------------|---|----------------------|---------------|--------|-----|-------|
|                      |                   |   |                      |               | MIN    | MAX |       |
| Input Offset Voltage | V <sub>IO1</sub>  | V <sub>CM</sub> = 0V  | 1                    | +25°C         | -6     | 6   | μV    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -8     | 8   | μV    |
|                      | V <sub>IO2</sub>  | V <sub>CM</sub> = 0V,<br>V <sub>OUT</sub> = 1.4V  | 1                    | +25°C         | -6     | 6   | μV    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -8     | 8   | μV    |
| Input Bias Current   | +I <sub>B1</sub>  | V <sub>CM</sub> = 0V,<br>+R <sub>S</sub> = 10kΩ,<br>-R <sub>S</sub> = 100Ω                          | 1                    | +25°C         | -100   | 100 | nA    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -125   | 125 | nA    |
|                      | -I <sub>B1</sub>  | V <sub>CM</sub> = 0V,<br>+R <sub>S</sub> = 100Ω,<br>-R <sub>S</sub> = 10kΩ                          | 1                    | +25°C         | -100   | 100 | nA    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -125   | 125 | nA    |
|                      | +I <sub>B2</sub>  | V <sub>CM</sub> = 0V, V <sub>OUT</sub> = 1.4V,<br>+R <sub>S</sub> = 10kΩ,<br>-R <sub>S</sub> = 100Ω | 1                    | +25°C         | -100   | 100 | nA    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -125   | 125 | nA    |
|                      | -I <sub>B2</sub>  | V <sub>CM</sub> = 0V, V <sub>OUT</sub> = 1.4V,<br>+R <sub>S</sub> = 100Ω,<br>-R <sub>S</sub> = 10kΩ | 1                    | +25°C         | -100   | 100 | nA    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -125   | 125 | nA    |
| Input Offset Current | I <sub>IO1</sub>  | V <sub>CM</sub> = 0V,<br>+R <sub>S</sub> = 10kΩ,<br>-R <sub>S</sub> = 10kΩ                          | 1                    | +25°C         | -10    | 10  | nA    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -20    | 20  | nA    |
|                      | I <sub>IO2</sub>  | V <sub>CM</sub> = 0V, V <sub>OUT</sub> = 1.4V<br>+R <sub>S</sub> = 10kΩ,<br>-R <sub>S</sub> = 10kΩ  | 1                    | +25°C         | -10    | 10  | nA    |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -20    | 20  | nA    |
| Common Mode<br>Range | +CMR <sub>1</sub> | V+ = +5V,<br>V- = -25V  | 1                    | +25°C         | 10     | -   | V     |
|                      |                   |   | 2, 3                 | +125°C, -55°C | 10     | -   | V     |
|                      | -CMR <sub>1</sub> | V+ = +25V,<br>V- = -5V  | 1                    | +25°C         | -      | -10 | V     |
|                      |                   |   | 2, 3                 | +125°C, -55°C | -      | -10 | V     |
|                      | +CMR <sub>2</sub> | V+ = +5V to +2V,<br>V- = 0V to -3V,<br>V <sub>OUT</sub> = 1.4V to -1.6V                             | 1                    | +25°C         | 3      | -   | V     |
|                      |                   |   | 2, 3                 | +125°C, -55°C | 3      | -   | V     |

## Specifications HA-5142/883

**TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

Device Tested at:  $R_{SOURCE} = 100\Omega$ ,  $R_{LOAD} = 500k\Omega$ ,  $V_{OUT} = 0V$ , Unless Otherwise Specified.

Subscript 1 Refers to Supply Voltages ( $V_{\pm}$ ) =  $\pm 15V$ , Subscript 2 Refers to  $V_{+} = 5.0$ ,  $V_{-} = 0V$

| PARAMETERS   | SYMBOL  | CONDITIONS   | GROUP A<br>SUBGROUPS | TEMPERATURE   | LIMITS |     | UNITS   |
|--|---|--|----------------------|---------------|--------|-----|---------|
|  |   |  |                      |               | MIN    | MAX |         |
| Large Signal Voltage<br>Gain                           | +A <sub>VOL1</sub>                                  | V <sub>OUT</sub> = 0V and +10V,<br>R <sub>L</sub> = 50k $\Omega$   | 4                    | +25°C         | 20     | -   | kV/V    |
|  |   |  | 5, 6                 | +125°C, -55°C | 15     | -   | kV/V    |
|  | -A <sub>VOL1</sub>                                  | V <sub>OUT</sub> = 0V and -10V,<br>R <sub>L</sub> = 50k $\Omega$   | 4                    | +25°C         | 20     | -   | kV/V    |
|  |   |  | 5, 6                 | +125°C, -55°C | 15     | -   | kV/V    |
|  | +A <sub>VOL2</sub>                                  | V <sub>OUT</sub> = 1.4V and 2.5V,<br>R <sub>L</sub> = 50k $\Omega$   | 4                    | +25°C         | 20     | -   | kV/V    |
|  |   |  | 5, 6                 | +125°C, -55°C | 15     | -   | kV/V    |
| Common Mode<br>Rejection Ratio                         | +CMRR <sub>1</sub>                                  | $\Delta V_{CM} = 10V$ ,<br>V <sub>+</sub> = 5V, V <sub>-</sub> = -25V,<br>V <sub>OUT</sub> = -10V                          | 1                    | +25°C         | 77     | -   | dB      |
|  |   |  | 2, 3                 | +125°C, -55°C | 77     | -   | dB      |
|  | -CMRR <sub>1</sub>                                  | $\Delta V_{CM} = 10V$ ,<br>V <sub>+</sub> = 25V, V <sub>-</sub> = -5V,<br>V <sub>OUT</sub> = +10V                          | 1                    | +25°C         | 77     | -   | dB      |
|  |   |  | 2, 3                 | +125°C, -55°C | 77     | -   | dB      |
|  | +CMRR <sub>2</sub>                                  | $\Delta V_{CM} = 0V$ to 3V,<br>V <sub>+</sub> = 2V, V <sub>-</sub> = -3V,<br>V <sub>OUT</sub> = -1.6V                      | 1                    | +25°C         | 77     | -   | dB      |
|  |   |  | 2, 3                 | +125°C, -55°C | 77     | -   | dB      |
| Output Voltage<br>Swing                                | +V <sub>OUT1</sub>                                  | R <sub>L</sub> = 50k $\Omega$  | 1                    | +25°C         | 10     | -   | V       |
|  |   |  | 2, 3                 | +125°C, -55°C | 10     | -   | V       |
|  | -V <sub>OUT1</sub>                                  | R <sub>L</sub> = 50k $\Omega$  | 1                    | +25°C         | -      | -10 | V       |
|  |   |  | 2, 3                 | +125°C, -55°C | -      | -10 | V       |
|  | +V <sub>OUT2</sub>                                  | R <sub>L</sub> = 50k $\Omega$<br>Terminated at 2.5V  | 1                    | +25°C         | 3.8    | -   | V       |
|  |   |  | 2, 3                 | +125°C, -55°C | 3.5    | -   | V       |
| -V <sub>OUT2</sub>                                     | R <sub>L</sub> = 50k $\Omega$<br>Terminated at 2.5V | 1  | +25°C                | -             | 1      | V   |         |
|  |   | 2, 3   | +125°C, -55°C        | -             | 1.2    | V   |         |
| Quiescent Power<br>Supply Current<br>(Both Amplifiers) | +I <sub>CC1</sub>                                   | V <sub>OUT</sub> = 0V, I <sub>OUT</sub> = 0mA  | 1                    | +25°C         | -      | 300 | $\mu A$ |
|  |   |  | 2, 3                 | +125°C, -55°C | -      | 400 | $\mu A$ |
|  | -I <sub>CC1</sub>                                   | V <sub>OUT</sub> = 0V, I <sub>OUT</sub> = 0mA  | 1                    | +25°C         | -300   | -   | $\mu A$ |
|  |   |  | 2, 3                 | +125°C, -55°C | -400   | -   | $\mu A$ |
|  | -I <sub>CC2</sub>                                   | V <sub>OUT</sub> = 1.4V,<br>I <sub>OUT</sub> = 0mA   | 1                    | +25°C         | -      | 160 | $\mu A$ |
|  |   |  | 2, 3                 | +125°C, -55°C | -      | 200 | $\mu A$ |
| Power Supply<br>Rejection Ratio                        | +PSRR <sub>1</sub>                                  | $\Delta V_{SUP} = +10V$ ,<br>V <sub>+</sub> = +10V, V <sub>-</sub> = -15V,<br>V <sub>+</sub> = +20V, V <sub>-</sub> = -15V | 1                    | +25°C         | 77     | -   | dB      |
|  |   |  | 2, 3                 | +125°C, -55°C | 77     | -   | dB      |
|  | -PSRR <sub>1</sub>                                  | $\Delta V_{SUP} = +10V$ ,<br>V <sub>+</sub> = +15V, V <sub>-</sub> = -10V,<br>V <sub>+</sub> = +15V, V <sub>-</sub> = -20V | 1                    | +25°C         | 77     | -   | dB      |
|  |   |  | 2, 3                 | +125°C, -55°C | 77     | -   | dB      |
|  | -PSRR <sub>2</sub>                                  | $\Delta V_{SUP} = +10V$ ,<br>V <sub>+</sub> = +5V, V <sub>-</sub> = 0V,<br>V <sub>+</sub> = +15V, V <sub>-</sub> = 0V      | 1                    | +25°C         | 77     | -   | dB      |
|  |   |  | 2, 3                 | +125°C, -55°C | 77     | -   | dB      |
| Channel Separation                                     | CS  | R <sub>L</sub> = 50k $\Omega$  | 1                    | +25°C         | 80     | -   | dB      |
|  |   |  | 2, 3                 | +125°C, -55°C | 80     | -   | dB      |

## Specifications HA-5142/883

**TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Tested at:  $R_{SOURCE} = 50\Omega$ ,  $R_{LOAD} = 50k\Omega$ ,  $C_{LOAD} = 50pF$ ,  $V_{OUT} = 0V$ ,  $A_V = 1V/V$ , Unless Otherwise Specified. Subscript 1 Refers to Supply Voltages ( $V_{\pm}$ ) =  $\pm 15V$ ; Subscript 2 Refers to  $V_+ = 5.0V$ ,  $V_- = 0.0V$ .

| PARAMETERS | SYMBOL           | CONDITIONS   | GROUP A SUBGROUPS | TEMPERATURE | LIMITS |     | UNITS      |
|------------|------------------|--|-------------------|-------------|--------|-----|------------|
|            |                  |  |                   |             | MIN    | MAX |            |
| Slew Rate  | +SR <sub>1</sub> | $V_{OUT} = -3V$ to $+3V$ ,<br>$V_{IN}$ S.R. $\leq 10V/\mu s$ | 4                 | +25°C       | 0.8    | -   | V/ $\mu s$ |
|            | -SR <sub>1</sub> | $V_{OUT} = +3V$ to $-3V$ ,<br>$V_{IN}$ S.R. $\leq 10V/\mu s$ | 4                 | +25°C       | 0.8    | -   | V/ $\mu s$ |
|            | +SR <sub>2</sub> | $V_{OUT} = 0V$ to $+3V$ ,<br>$V_{IN}$ S.R. $\leq 10V/\mu s$  | 4                 | +25°C       | 0.8    | -   | V/ $\mu s$ |
|            | -SR <sub>2</sub> | $V_{OUT} = +3V$ to $0V$ ,<br>$V_{IN}$ S.R. $\leq 10V/\mu s$  | 4                 | +25°C       | 0.8    | -   | V/ $\mu s$ |

**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Tested at:  $R_{SOURCE} = 50\Omega$ ,  $R_{LOAD} = 50k\Omega$ ,  $C_{LOAD} = 50pF$ ,  $A_V = 1V/V$ , Unless Otherwise Specified. Subscript 1 Refers to Supply Voltages ( $V_{\pm}$ ) =  $\pm 15V$ ; Subscript 2 Refers to  $V_+ = 5.0V$ ,  $V_- = 0.0V$ .

| PARAMETERS                      | SYMBOL            | CONDITIONS                              | NOTES | TEMPERATURE     | LIMITS |     | UNITS |
|---------------------------------|-------------------|---|-------|-----------------|--------|-----|-------|
|                                 |                   |   |       |                 | MIN    | MAX |       |
| Full Power Bandwidth            | FPBW <sub>1</sub> | $V_{PEAK} = 10V$                        | 1, 2  | +25°C           | 12.7   | -   | kHz   |
|                                 | FPBW <sub>2</sub> | $V_{PEAK} = 1.1V$ ,<br>$V_{REF} = 2.5V$ | 1, 2  | +25°C           | 115.8  | -   | kHz   |
| Minimum Closed Loop Stable Gain | CLSG              | $R_L = 50k\Omega$ , $C_L = 50pF$        | 1     | -55°C to +125°C | 1      | -   | V/V   |
| Quiescent Power Consumption     | PC <sub>1</sub>   | $V_{OUT} = 0V$ , $I_{OUT} = 0mA$        | 1, 3  | -55°C to +125°C | -      | 12  | mW    |
|                                 | PC <sub>2</sub>   | $V_{OUT} = 1.4V$ ,<br>$I_{OUT} = 0mA$   | 1, 3  | -55°C to +125°C | -      | 1   | mW    |

**NOTES:**

- Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
- Full Power Bandwidth guarantee based on Slew Rate measurement using  $FPBW = \text{Slew Rate}/(2\pi V_{PEAK})$ .
- Quiescent Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.)

**TABLE 4. ELECTRICAL TEST REQUIREMENTS**

| MIL-STD-883 TEST REQUIREMENTS               | SUBGROUPS (SEE TABLES 1 AND 2) |
|---|--------------------------------|
| Interim Electrical Parameters (Pre Burn-In) | 1                              |
| Final Electrical Test Parameters            | 1 (Note 1), 2, 3, 4, 5, 6      |
| Group A Test Requirements                   | 1, 2, 3, 4, 5, 6               |
| Groups C and D Endpoints                    | 1                              |

**NOTE:**

- PDA applies to Subgroup 1 only.

**Die Characteristics**

**DIE DIMENSIONS:**

104 x 55 x 19 mils ± 1 mils  
 2650 x 1400 x 483µm ± 25.4µm

**METALLIZATION:**

Type: Al, 1% Cu  
 Thickness: 16kÅ ± 2kÅ

**GLASSIVATION:**

Type: Nitride (Si3N4) over Silox (SiO2, 5% Phos.)  
 Silox Thickness: 12kÅ ± 2kÅ  
 Nitride Thickness: 3.5kÅ ± 1.5kÅ

**WORST CASE CURRENT DENSITY:**

0.6 x 10<sup>5</sup>A/cm<sup>2</sup>

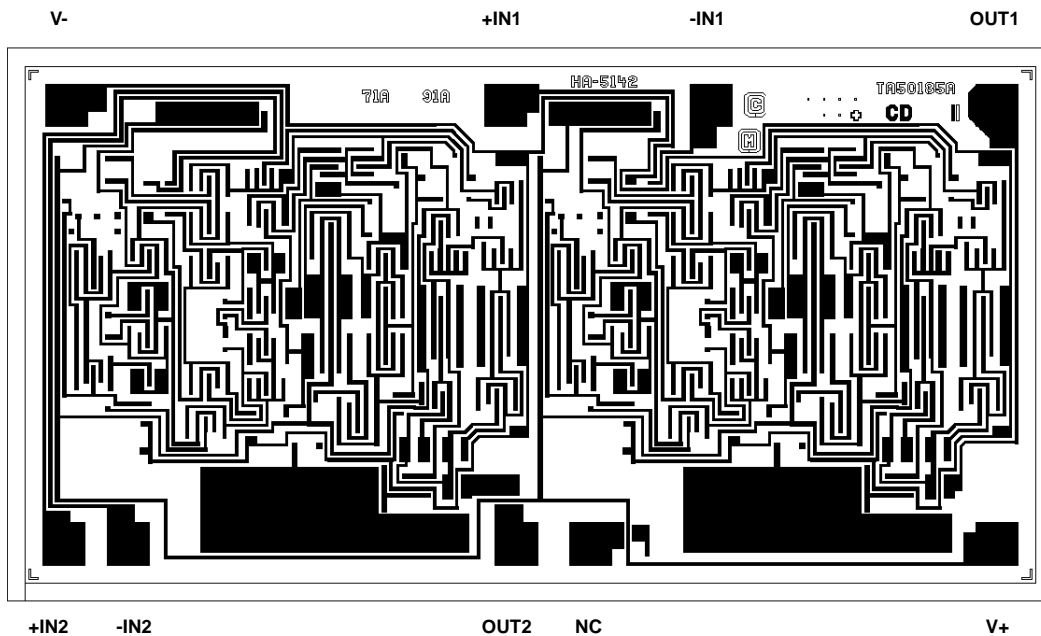
**SUBSTRATE POTENTIAL (Powered Up):** V-

**TRANSISTOR COUNT:** 72

**PROCESS:** Bipolar/JFET Dielectric Isolation

**Metallization Mask Layout**

HA-5142/883



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